

# Design and Analysis of High Performance Operational Transconductance Amplifier

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**Abstract-** This paper presents a high performance Operational Transconductance Amplifier (OTA) that combines two linearization techniques, and one gain enhancement technique. The two linearization technique are adaptive biasing of differential pairs and resistive source degeneration. The gain enhancement technique is Common mode feedback Amplifier. The Operational Transconductance Amplifier has  $\pm 0.9v$  power supply. Operational Transconductance Amplifier has been simulated with TANNER 0.18 $\mu m$  CMOS technology in Tspice. The simulated third order harmonic distortion (HD3) with applying a 300mvP-P differential input, remains below -60dB at 3MHz frequency, also the simulation result gives Transconductance gain(gm) 5.247mA/V for 10mV(p-p) input voltage.

**Index Terms-** Operational Transconductance Amplifier (OTA); linearity; adaptive bias circuit; source degeneration; CMFB circuit.

## I. INTRODUCTION

Operational Transconductance Amplifier (OTA) is a fundamental building block of analog circuits and systems. OTA has been used to implement many kinds of analog circuits such as; opamps, data converters, four-quadrant multipliers, mixers, modulators and continuous-time filters [1]-[10]. In such application as asymmetrical digital subscriber lines (ADSL) and cable-modem, the linearity has to be 60dB while for example, video applications require at least 60dB of linearity at 5MHz [5]. Gm-C topology is a good choice for realizing continuous-time filter has better performance in frequency response and electronic tuning capability, but suffer from poor linearity[5]-[8]. Thus designing an OTA with high linearity and high Transconductance gain tends to be a constraint in circuits and systems design task.

In literatures several techniques have been presented to design Operational Transconductance Amplifier to achieve Transconductance gain as well as Linearity. The Transconductance gain has been improved by using three stage amplifier circuit. In [3] utilizing a tail current depends on the square of input differential signal, linearity in output current of strong inversion transconductor has been improved. This technique which is known as adaptive bias technique loses its performance due to second order effects in modern nano scale devices. Source/gate degeneration is another technique for linearity enhancement, specially in nano scale CMOS technology which the HD3 due to mobility reduction effect is considerable [2]. Some other techniques use two or multiple Gm cell to cancel

third order harmonic distortion [4]-[9]. Double Differentia Pair (DDP) is one of these techniques that uses two cross coupled differential pairs. Then choosing proper sizing and tail current biases can cancel the third order harmonic. The main drawback of these techniques is higher power consumption and transconductance loss [4].

In this paper we combine adaptive bias [12], source degeneration techniques and Common Mode Feedback circuit to improve the linearity and Transconductance gain of a OTA. A well accurate-precise analog processing requires a pure wanted signal. This means that the required signal is distortion free and interference free (common mode signal). Consequently to ensure the best processing condition high linear signal. the point which seems to be less regarded in most works so far. Therefore in this work the Improved adaptive bias circuit and common mode feedback circuit is used to provide a high linearity and high gain. In section II we propose the principle and theoretical relations of these linearization techniques. In section III complete linear OTA and theoretical relation for high Transconductance gain is shown. In section IV simulation results are given and in section V we conclude the paper.

## II. PRINCIPLE OF LINEAR TRANSCONDUCTOR

Fig. 1 shows a source-coupled n-channel differential pair that is biased by current tail  $I_{SS}$ . In this figure  $vin1$  and  $vin2$  are input signals including both common and differential modes. The large-signal i-v transfer characteristic will be given by:

$$I_{out} = I_{D1} - I_{D2} = \frac{1}{2} \beta_{vin} \sqrt{\frac{4I_{SS}}{\beta} - vin^2} \quad |V_{in}| \leq \sqrt{\frac{2I_{SS}}{\beta} - (1-a)}$$

$$I_{D1} - I_{D2} = \frac{I_{SS}}{W} \text{sgn}(vin) \quad |V_{in}| > \sqrt{\frac{2I_{SS}}{\beta} - (1-b)}$$

$$\beta = \mu_n c_{ox} \frac{W}{L}, \quad v_{in} = v_{in1} - v_{in2} \quad (1)$$

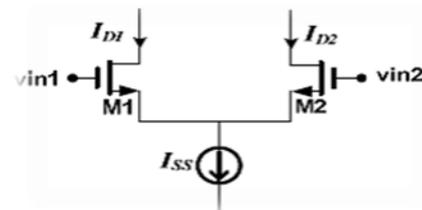


Figure 1: Simple differential pair.

In (1)  $vin$  is differential input ( $vin1-vin2$ ) and “sgn” is sign function. Other parameters in (1) have their usual meanings. For



### III. PROPOSED OTA

With reference to principles explained in section II the complete fully differential OTA which benefits from the source degeneration and adaptive bias techniques as well as a CMFB circuit shown in Fig. 4.

In this circuit  $\alpha=4$ ,  $n=2.16$ ,  $I=20\mu A$  and  $I_{CSS}=10\mu A$ . To avoid from drawbacks associated with resistive source degeneration which mentioned before, small resistors ( $R=210\Omega$ ) is used. The CMFB circuit sense the CM level of the two outputs and accordingly adjust one of the bias current in Operational Transconductance Amplifier.

From fig. 4  $\beta$  is closed loop feedback factor.

$$\beta = \frac{V_{out+}}{V_{out-}} \Big|_{i_{out-} = 0} \quad (12)$$

$$\beta = -(gm_{13} + gm_{14})(Ron_{13} \parallel Ron_{14})$$

$$\beta = 2\mu_n c_{ox} \left(\frac{W}{L}\right)_{13,14} \frac{1}{(2\mu_n c_{ox} \left(\frac{W}{L}\right)_{13,14}) \cdot (V_{GS13,14} - V_{TH13,14})}$$

$$\beta = \frac{V_{DS13,14}}{(V_{GS13,14} - V_{TH13,14})}$$

where  $V_{GS13,14} - V_{TH13,14}$  denotes the overdrive voltage of  $M_{13}$

and  $M_{14}$ . Thus  $\left| \frac{dV_{out,CMFB}}{dV_b} \right| = \frac{V_{GS13,14} - V_{TH13,14}}{V_{DS13,14}}$

Since  $V_{GS13,14}$  (i.e. the output CMFB) is typically in the vicinity of  $V_{DD}/2$ , The above eq. suggest that  $V_{DS13,14}$  must be maximized.

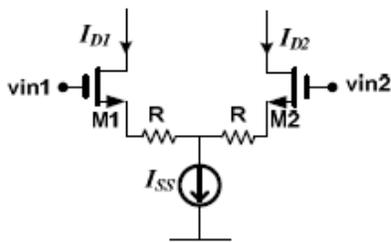


Figure 3: Source degeneration for linearity enhancement.

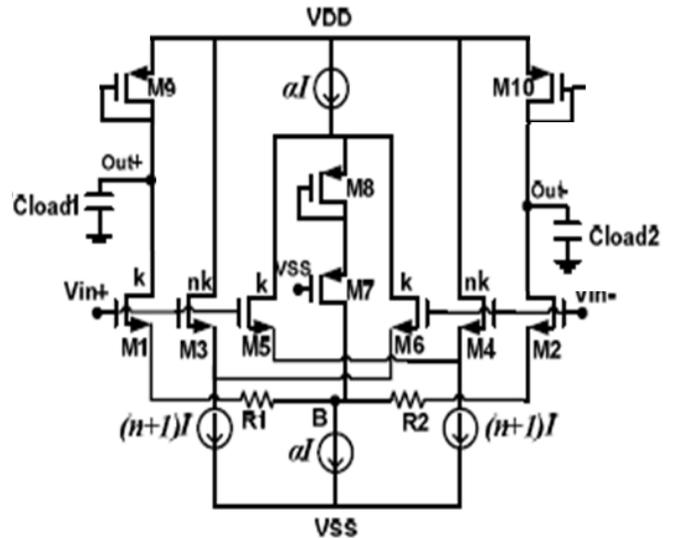
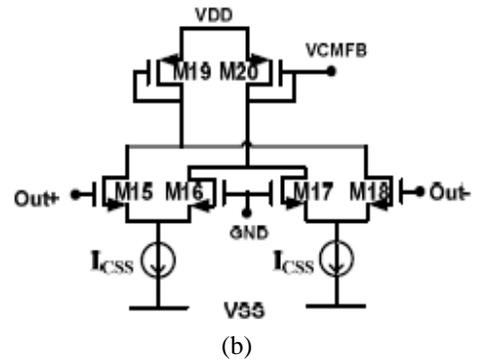


Figure 4 (a) Proposed linear OTA. (b) CMFB circuit

The simulation result show that improved version of adaptive bias circuit and source degeneration circuit provide linearity with coefficient of correlation ( $r^2$ ) = .9894.

### IV. SIMULATION RESULTS

The proposed OTA (Fig. 4(a)) have been simulated using the standard  $0.18\mu m$  CMOS technology in Tspice simulator. Power supply of the circuit is  $\pm 0.9V$ . Applying an input signal with frequency near to unity gain frequency (3MHz), HD3 of output current in capacitance loads versus magnitude of input signal with source degeneration and adaptive bias technique is shown In fig. 6-a. The value of peak-to-peak differential current in capacitance load ( $i_{Load1} - i_{Load2}$ ) is also shown in fig. 6-b.

Fig. 7 shows transconductance gain versus differential input signal that verifies the minimum difference voltage gives high gain. Table I shows the main specifications of proposed OTA compared with some similar works.

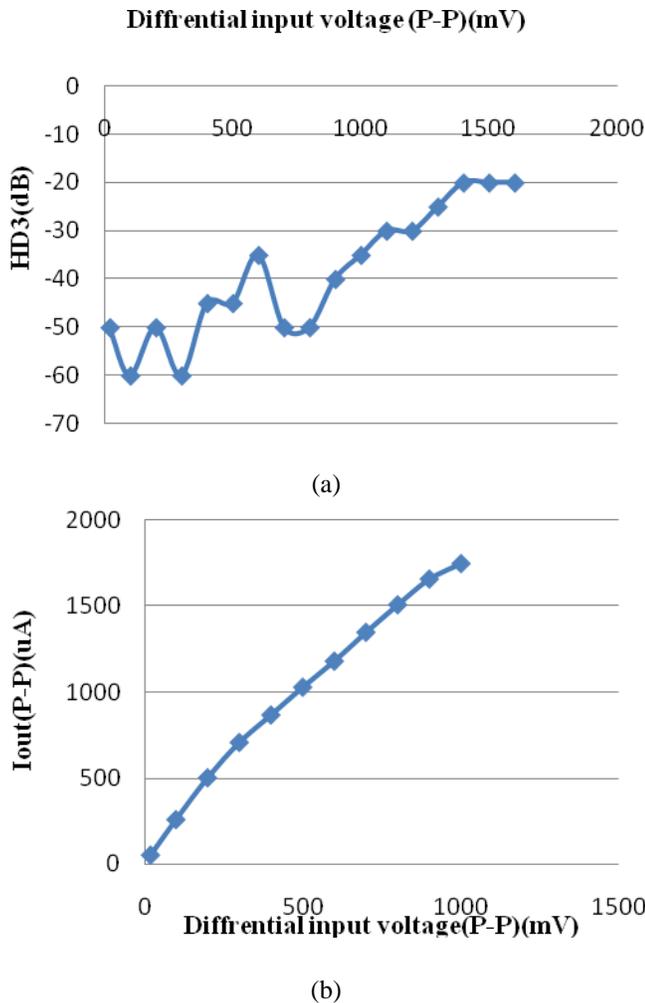


Figure 6: (a) HD3 of output current using adaptive bias technique and source degeneration with  $R= 210\Omega$ . (b) Peak to Peak differential output current which gives coefficient of correlation( $r^2$ ) = .9892.

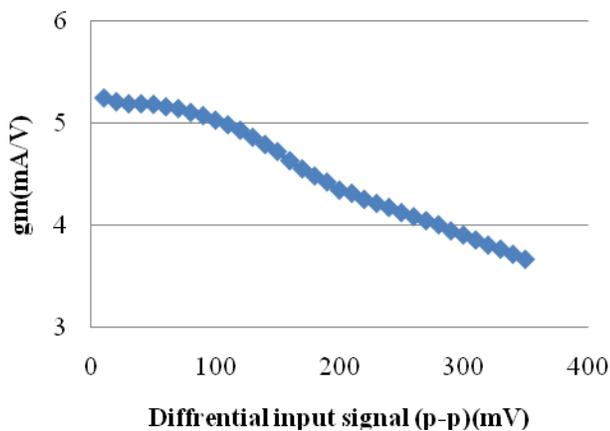


Figure 7: Transconductance gain, versus differential input signal.

Table I. Specifications of Proposed OTA Compared With Similar Works.

Specification	This work	[15]	[9]	[10]
Technology	0.18um	0.18um	0.18um	0.18um
Supply voltage	0.9V	1V	1.8V	1.1V
DC gain	45dB	NA	NA	63dB
Transconductance gain(gm)	5.247mA/V	100 uA/V	20 uA/V	NA
Linearity	HD3= -60 dB 0.3Vp-p at 3MHz	HD3= -55dB 0.7Vp-p at 30MHz	HD3= -65 dB 0.6Vp-p at 1MHz	THD= -62 dB 1Vp-p at 100KHz

## V. CONCLUSION

In this paper we proposed a highly linear OTA which combines two linearization techniques and one gain enhancement technique. An improved Adaptive bias circuitry and source degeneration with low resistance ( $210\Omega$ ) is utilized to improve the linearity in nano scale CMOS technology. Using small resistors makes this circuit suitable for low voltage low-power application. OTA has been simulated with  $0.18\mu\text{m}$  CMOS technology in Tspice. The simulated third order harmonic distortion (HD3) with a  $300\text{mVp-p}$  differential input remains below  $-60\text{dB}$  for frequency up to  $3\text{MHz}$  which gives coefficient of correlation( $r^2$ ) = .9892 also the simulation result gives Transconductance gain(gm)  $5.247\text{mA/V}$  for  $10\text{mV(p-p)}$  input voltage.

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